



University of Tabriz

OFET

Organic

Field

Effect

Transistor

of Hamed Fooladvand

Supervised by Dr. Kiyani





University of Tabriz

Article history:

Received 23 December 2011

Received in revised form 16 June 2012

Accepted 20 August 2012

Available online 15 September 2012

Microelectronic Engineering March 2013, Pages 111–117



A paper describing

Use of side chain thiophene containing copolymer as a non-ionic gel-dielectric material for sandwich OFET assembly

Busra Sengez ^a, Zekeriya Dog̃ruyol ^b, Sait E. San ^c, Arif Kosemen ^c, Faruk Yılmaz ^a, Mustafa Okutan ^b, Yusuf Yerli ^c, Ahmet Demir ^c, Engin Basaran ^d

^a Department of Chemistry, Gebze Institute of Technology, Kocaeli 41400, Turkey

^b Department of Physics, Yıldız Technical University, _Istanbul 34220, Turkey

^c Department of Physics, Gebze Institute of Technology, Kocaeli 41400, Turkey

^d Department of Engineering Physics, _Istanbul Medeniyet University, _Istanbul 34720, Turkey



University of Tabriz

CONTENTS

- ❖ **INTRODUCTION**
- ❖ **MATERIALS & SYNTHESIS**
- ❖ **OFET FABRICATION**
- ❖ **RESULTS & DISCUSSION**
- ❖ **Future Applications of OFET**



INTRODUCTION

University of Tabriz

- ❖ **Organic Field-effect Transistor (OFET)** is a three terminal device whose characteristics can be modulated by the electrical field.
- ❖ It is composed of **organic conjugated molecules** as active channels, **inorganic** or **polymer insulators** as dielectric layer and **metals** as electrodes.



University of Tabriz

INTRODUCTION

- ❖ Among the many soluble polymers, **regio-regular poly(3-hexylthiophene) (rr-P3HT)** has been extensively studied in organic field-effect transistors (OFETs) due to its comparatively **high hole carrier mobility, simple solution process ability, and commercial availability.**
- ❖ Also, The use of organic dielectric polymers such as **PMMA** has generally resulted with relatively **high mobility and better device reliabilities** compared to that of the highly process dependent **SiO₂.**



University of Tabriz

INTRODUCTION

Aim of this Paper

- ❖ The aim of this work briefly is to **realize sandwich-processed OFETs** operating at low supply voltages and so, **enhance the field effect mobility** with use of appropriate **gel copolymer gate dielectric** for future organic circuit applications.
- ❖ For this purpose, **P3HT** based OFET assembly with **gel-PMMA/PC** dielectric was compared with that containing **gel-P(MMA-co-MTM)/PC** dielectric.



University of Tabriz

INTRODUCTION

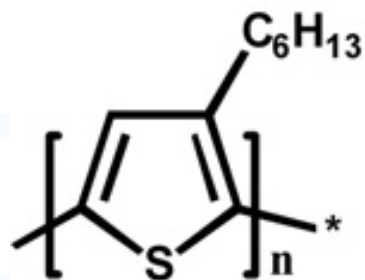
Aim of this Paper

- ❖ At the same time it was demonstrated for the first time that the fabrication of thiophene-based dielectric material by integration of PC, **without any polyelectrolyte containing anion groups**, as a gate non-ionic-gel-gated OFET (a so-called non-ionic gel-OFET).
- ❖ The inspiration of This approach mainly targets on the exploitation of **interfacial effects** by a novel dielectric copolymer for better compatibility, which is supposed to provide **better output characteristics** in the device.

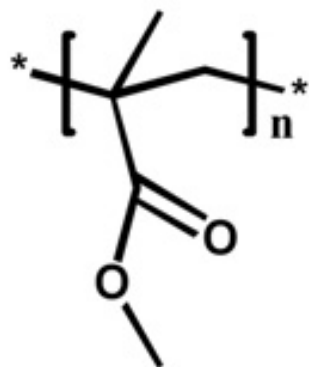


MATERIALS

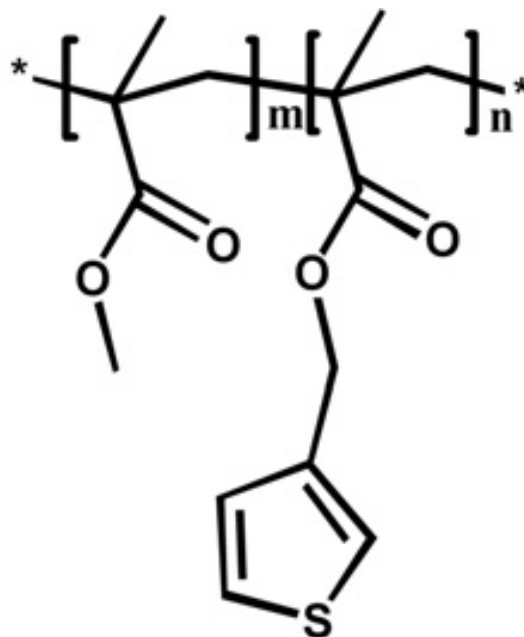
University of Tabriz



P3HT

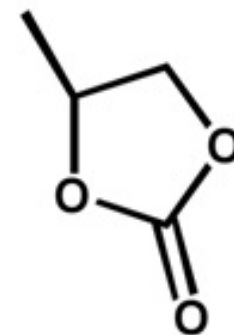


PMMA



methylthienyl methacrylate

P(MMA-co-MTM)



PC

Propylene carbonate

❖ The chemical structures of the polymers and propylene carbonate used in this study



SYNTHESIS

University of Tabriz

❖ Composition data for free-radical copolymerization of MMA with MTM

	Molar ratio (MMA\MTM)	Components ratio ^a (MMA\MTM) (%)	Efficiency ^b (%)	M _n ^c (g/mol)	PDI ^c
P(MMA-co-MTM)	3\1	74\26	49.7	68261	2.24

[AIBN]/Monomers = 1×10^{-2} , time = 3 h, temperature = 65 °C.

^a Obtained from ¹H-NMR spectroscopy.

^b Overall monomer conversion.

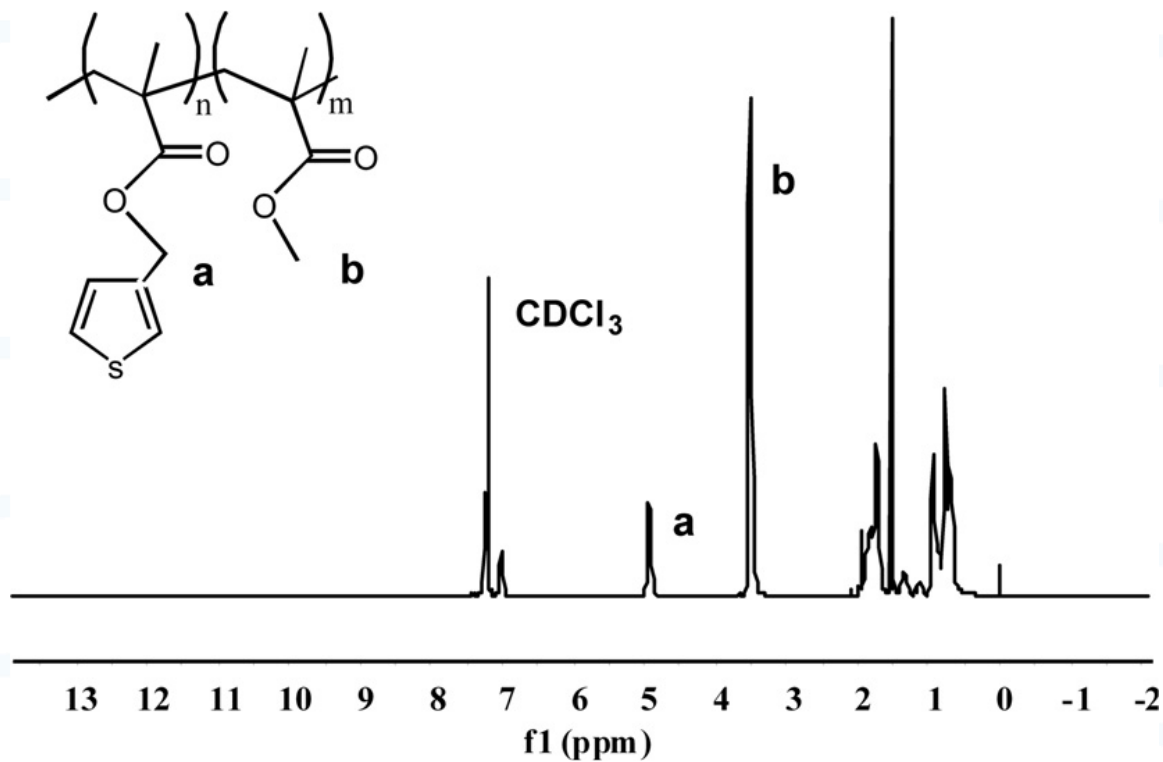
^c Determined by GPC based on PMMA standards.



SYNTHESIS

University of Tabriz

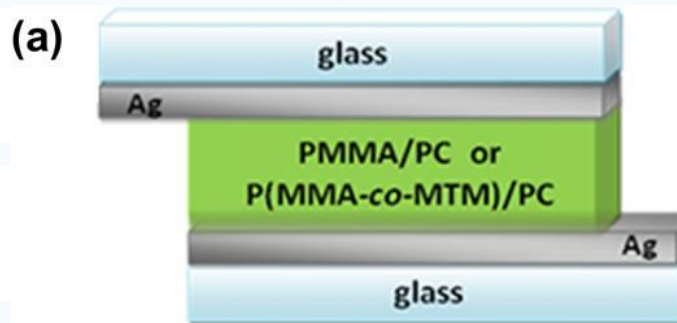
❖ H-NMR spectrum of Poly(MMA-co-MTM).



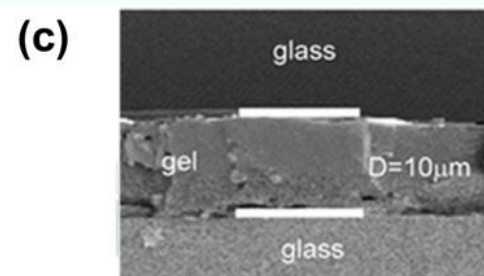


University of Tabriz

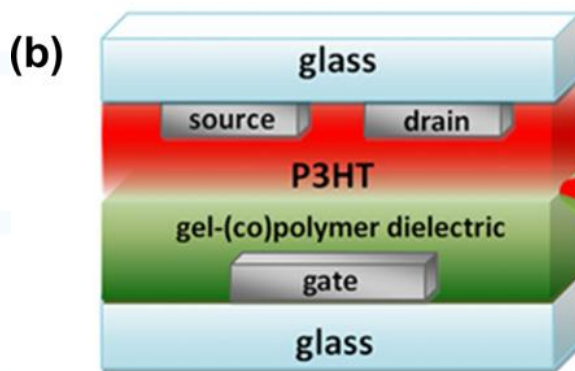
OFET FABRICATION



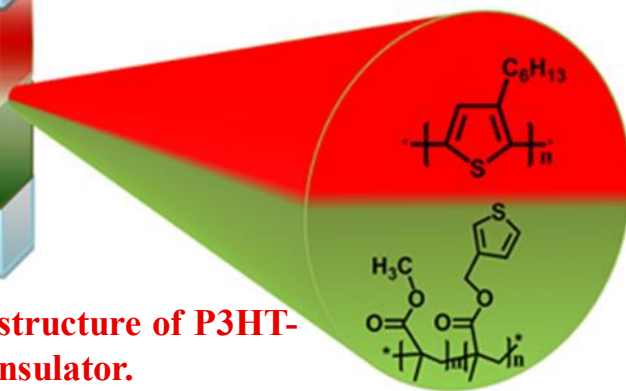
(a) Schematic illustration of a capacitor with silver electrode



(c) SEM image of gel thickness



(b) Schematic illustration of device structure of P3HT-OFET with non-ionic-gel as a gate insulator.





University of Tabriz

OFET FABRICATION (at Labratoary)

www.youtube.com/watch?v=PE8Att1iiFA



**Organic Field Effect Transistors:
Fabrication and Characterization**

Shree Prakash Tiwari, Georgia Institute of Technology



University of Tabriz

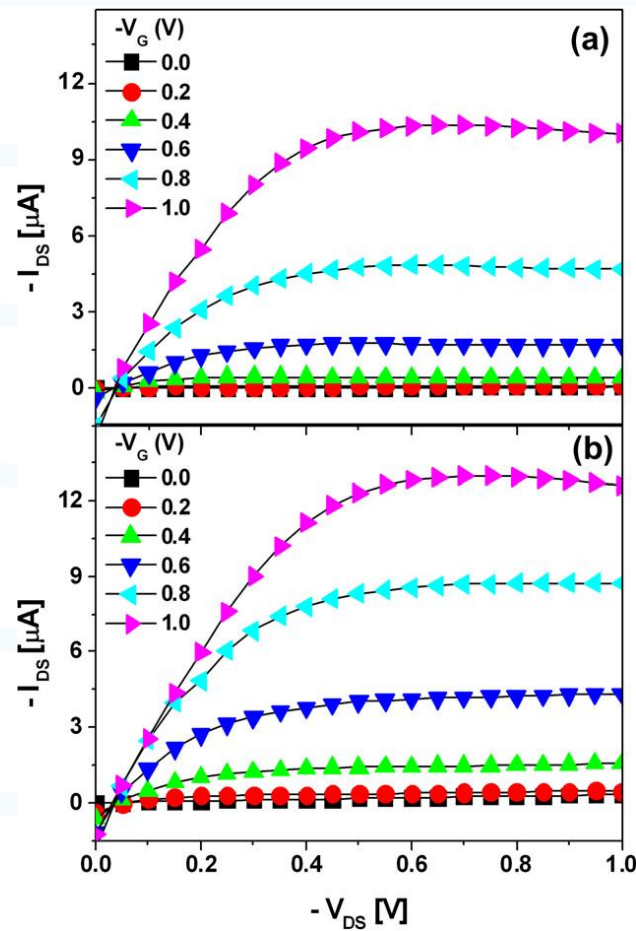
RESULTS & DISCUSSION

Output characteristics

❖ Output characteristics of both P3HT-OFETs

a) gel-PMMA/PC

b) gel-P(MMA-co-MTM)/PC





RESULTS & DISCUSSION

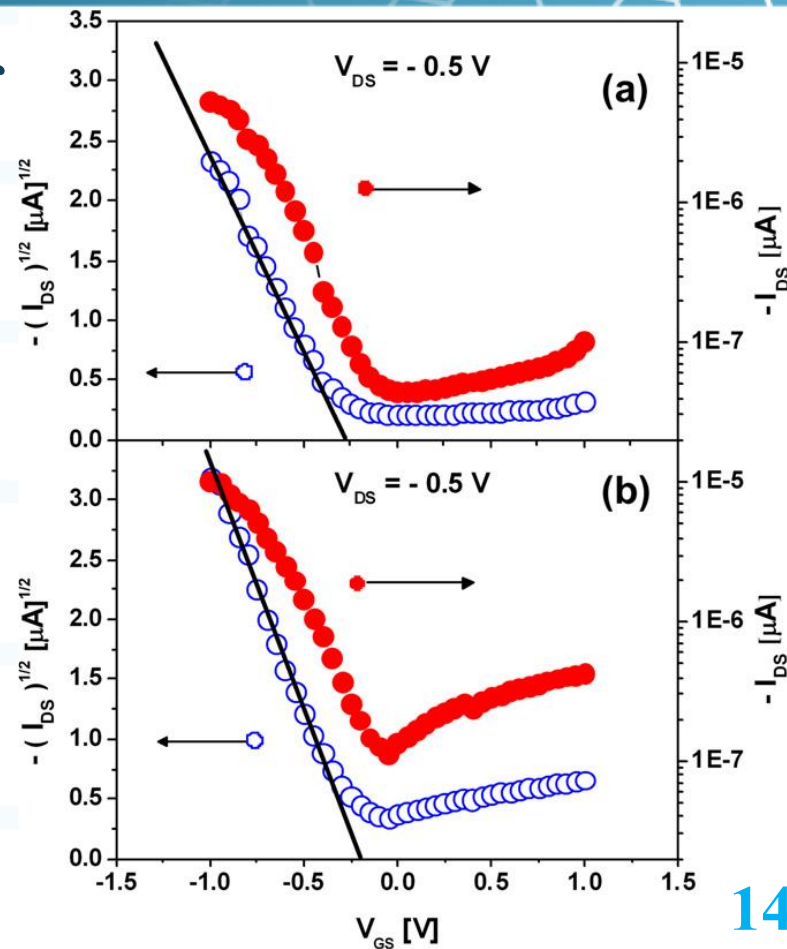
Transfer characteristics

University of Tabriz

❖ Transfer characteristics of both P3HT-OFETs

a) gel-PMMA/PC

b) gel-P(MMA-co-MTM)/PC





University of Tabriz

Future Applications of OFET

Application of OFET in Smart Phone

Application of OFET in Display





University of Tabriz

My God is My HERO ... !

WITHOUT HIM THIS WORLD WOULD BE EMPTY ...

**Thanks a Lot
For Your Attention**

**THE
END**